

# High-frequency fluctuational conductivity in $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$

E.Silva<sup>(1)</sup>, R.Marcon<sup>(1)</sup>, R. Fastampa<sup>(2)</sup>, M. Giura<sup>(2)</sup>, S. Sarti<sup>(2)</sup>

<sup>(1)</sup>*Dipartimento di Fisica “E.Amaldi” and Unità INFM,  
Università “Roma Tre”, Via della Vasca Navale 84, 00146 Roma, Italy*

<sup>(2)</sup>*Dipartimento di Fisica and Unità INFM,  
Università “La Sapienza”, P.le Aldo Moro 2, 00185 Roma, Italy  
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We present measurements of the fluctuational excess conductivity at 48 GHz and 24 GHz in  $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$  films above the transition temperature. The measurements depart from the gaussian prediction for finite-frequency fluctuational conductivity. We focus on the region not too close to  $T_c$ , where the real part of the excess conductivity drops much faster than the prediction of the gaussian model. We calculate the dynamic excess conductivity within a Ginzburg-Landau approach. In the calculation we insert a short-wavelength cutoff of the order of the inverse coherence length, in order to suppress high-momentum modes. The excess conductivity of all samples measured can be described very well by the modified model.

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High- $T_c$  superconductors are model systems for the study of superconducting fluctuations. High transition temperatures, short coherence lengths and anisotropy contribute to unveil fluctuative regimes that are hindered in conventional superconductors. In fact, in the latter the superconducting fluctuations are rather well described in terms of relatively simple models, such as (focussing on the electrical transport) the Aslamazov and Larkin theory<sup>1</sup> (in a microscopic framework) or gaussian models.<sup>2</sup>

A large part of the experiments on transport properties in the fluctuational region have been performed by measuring the dc electrical conductivity.<sup>3,4</sup> While this approach benefits from the higher precision of dc measurements, it is intrinsically unable to give information on the characteristic time of the fluctuations, as opposed to the dynamic conductivity.<sup>5</sup> It is then interesting to examine appropriate tools for the analysis of the dynamic conductivity.

Most of such models have been developed to hold in a temperature region neither too close to  $T_c$  (that is, outside of the critical region), nor too far from  $T_c$  (where the single  $q=0$  fluctuation mode is supposed to fully describe the system). Due to the wide temperature region where fluctuation effects are observed in high- $T_c$  cuprates, these simple models have been recently reexamined.<sup>6,7</sup> In this paper we focus on the analysis of the temperature region not too close to  $T_c$ , introducing a simple Ginzburg-Landau (GL) model for the finite-frequency excess conductivity. We then discuss our microwave data for the excess conductivity in light of the proposed extension to the gaussian theory.

We briefly sketch the theoretical approach. We derive the (a,b)-plane complex conductivity within the correlation function formalism, using the GL functional written for a three-

dimensional uniaxial anisotropic superconductor, and limited to terms containing  $\psi^2$ . We do not attempt here to include the quartic term since its effect becomes relevant only very close to  $T_c$ . The dynamic of the order parameter, introduced through the time-dependent GL theory, is governed by  $w = \omega\tau_0/\epsilon$ , where  $\omega/2\pi$  is the measuring frequency,  $\epsilon = \ln(T/T_c)$  is the reduced temperature,<sup>8</sup> and  $\tau_0$  is the temperature-independent GL relaxation time.<sup>9</sup> The complex conductivity is obtained by averaging the current operator with respect to the noise as  $\langle J_{ab}(t) \rangle = -\frac{\hbar e^*}{m_{ab}} \int \frac{d^3q}{(2\pi)^3} q_{ab} C[\mathbf{k} = \mathbf{q} - \frac{e^*}{\hbar} \mathbf{A}(t); t, t]$ , where  $C$  is the order-parameter correlator,  $\mathbf{A}$  is the harmonic vector potential,  $e^* = 2e$  is twice the electronic charge, and  $m_{ab}$  is the in-plane mass of the pair. Since<sup>5</sup>  $\tau_0 \sim 20$  fs, a small- $w$  expansion is appropriate. The common approach involves integration of the expression for the current over all  $q$  values, since the  $q=0$  mode is the most diverging close to  $T_c$ . The result is the well-known gaussian result by Schmidt:<sup>2</sup>

$$\Delta\sigma_g = \Delta\sigma_{1,g} + i\Delta\sigma_{2,g} \simeq \Delta\sigma_0 \left[ \left(1 - \frac{w^2}{16}\right) + i\frac{w}{6} \right] \quad (1)$$

where  $\Delta\sigma_0 = \frac{e^2}{32\hbar\xi_c(0)\epsilon^{1/2}}$  is the gaussian, dc excess conductivity, and  $\xi_c(0)$  is the zero temperature out-of-plane GL coherence length. When temperature raises above  $T_c$ , the relative weight of the  $q \neq 0$  modes increases. However modes with  $q$  higher than, e.g., the inverse coherence length should not be allowed. The customary way to take into account this feature is to put a cutoff in the integration of the current operator (see an extended discussion in Ref.<sup>7</sup>). Using a single cutoff such that  $\sqrt{\sum_{j=a,b,c} [q_j^{max}\xi_j(0)]^2} < \Lambda$ , the dynamic (cutoffed) excess conductivity becomes (for small  $w$ ):<sup>10</sup>

$$\Delta\sigma_{1,c} \simeq \Delta\sigma_0 \left\{ \frac{2}{\pi} \left[ atnK - \frac{K}{(1+K^2)^2} \left(1 + \frac{5}{3}K^2\right) \right] + o(w^2) \right\} \quad (2)$$

$$\Delta\sigma_{2,c} \simeq \Delta\sigma_0 \frac{w}{6} \frac{2}{\pi} \left[ atnK + \frac{K}{(1+K^2)^3} \left(K^4 - \frac{8}{3}K^2 - 1\right) \right] \quad (3)$$

where  $K = \Lambda/\epsilon^{\frac{1}{2}}$ . We note that the frequency dependence remains unaltered with respect to the gaussian expression, while the temperature dependence changes due to the cutoff effects. In Fig.1a we plot a simulation of  $\Delta\sigma_{1,c}/\Delta\sigma_{1,g}$  and  $\Delta\sigma_{2,c}/\Delta\sigma_{2,g}$  as a function of  $\epsilon$ , for cutoff number  $\Lambda=0.5$ , and neglecting all but the leading term in the expressions for  $\Delta\sigma$ . It is immediately seen that the cutoff effects, if present, are best visible in  $\Delta\sigma_1$ .

We have measured the microwave response at 23.9 and 48.2 GHz in two YBa<sub>2</sub>Cu<sub>3</sub>O<sub>7- $\delta$</sub>  films, grown by different techniques. In all cases the film was the end wall of a cylindrical metal cavity, resonating in the TE<sub>011</sub> mode. Details of the technique have been given elsewhere.<sup>11</sup> Measurements of the quality factor yielded the effective surface resistance  $R$ . The measured films were thinner than 2500 Å, so that in the transition region  $R \simeq \rho_1/d$ , where  $\rho_1$  is the real part of the resistivity and  $d$  is the film thickness.<sup>12</sup>

In one sample (measured at 48.2 GHz) we have carefully measured the frequency shift near the transition, in order to obtain the effective surface reactance  $X \simeq \rho_2/d$ , where  $\rho_2/d$  is the imaginary part of the resistivity. The data are reported in Fig.2a. We discuss with some

length these data, in order to illustrate the main aspects of the analysis. The complex excess conductivity  $\Delta\sigma$  is defined as follows:

$$\rho_1 + i\rho_2 = \frac{1}{\sigma_n + \Delta\sigma} \quad (4)$$

where  $\rho_n = \frac{1}{\sigma_n}$  is the normal state resistivity, that we take as the linear extrapolation from high temperatures. The inversion of Eq.4 gives  $\Delta\sigma_1$  and  $\Delta\sigma_2$ , that are reported as a function of  $T$  in Fig.2b. Such data are first used to evaluate  $T_c$ , using the scaling theories<sup>13</sup> prediction  $\Delta\sigma_1(T_c) = \Delta\sigma_2(T_c)$ . Since  $\Delta\sigma_2$  is vanishingly small  $\sim 1$  K above  $T_c$ , we can approximate  $\Delta\sigma_1 \simeq \frac{1}{\rho_1} - \frac{1}{\rho_n}$  not too close to  $T_c$ . The result is reported in Fig.2c, and compared to the exact inversion of the  $\rho$  data. As can be seen, above  $1.01 T_c$  the two procedures yield the same result. This feature can be put on quantitative grounds by plotting the percentage deviation of the approximate from the exact derivation of  $\Delta\sigma_1$ , as in Fig.2d. It is seen that the deviation is largely below 5% for  $T - T_c > 0.5$  K.

From this discussion of these data, we can assert that the  $w \simeq 0$  regime for  $\Delta\sigma_1$  is reached in a wide temperature range, even at our highest measuring frequency of 48.2 GHz.

On the basis of the previous discussion, we have extracted in the second sample  $\Delta\sigma_1$  with the approximate expression, and we have used the inflection point of  $\rho_1$  to estimate  $T_c$  (we note that the precise choice of  $T_c$  does not significantly affect the data analysis in the range of interest here,  $\epsilon > 10^{-2}$ ). In Fig.1b we report the ratio  $\Delta\sigma_1/\Delta\sigma_0$ , having used  $\xi_c(0)$  as a scale factor in order to get the correct limit at low  $\epsilon$ . These data show a clear evidence for the failure of the simple gaussian approximation, which predicts a constant value for all  $\epsilon$ . In the same Fig.1b, continuous lines are fits performed through Eq.2, in good agreement with the data. We can conclude that our measurements of the excess conductivity, performed at microwave frequencies, show clear departures from the gaussian prediction, and that the correction is well described by the introduction of a cutoff in the spectrum of accessible momenta.

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# FIGURES

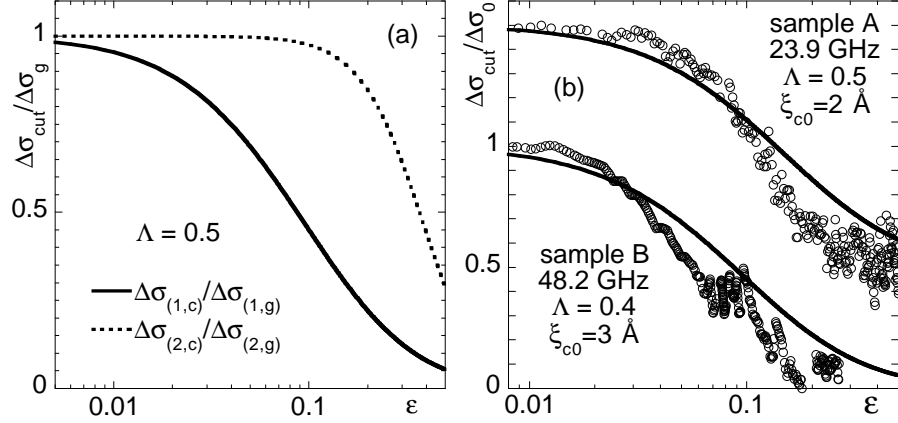


FIG. 1. (a) Ratios of  $\Delta\sigma_{1,c}/\Delta\sigma_{1,g}$  (continuous line) and  $\Delta\sigma_{2,c}/\Delta\sigma_{2,g}$  (dashed line) for  $\Lambda=0.5$ . It is seen that the cutoff correction is significant only on the real part. (b) Experimental ratios of  $\Delta\sigma_1/\Delta\sigma_0$  (open symbols), together with the fits with the cutoffed expression.

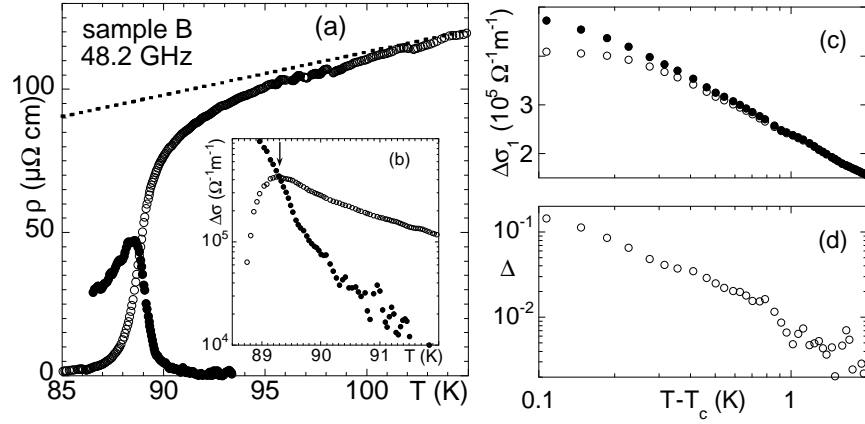


FIG. 2. Panel (a): microwave resistivity measured at 48.2 GHz in sample B. Open symbols,  $\rho_1$ ; full dots,  $\rho_2$ ; dashed line,  $\rho_n$ . Panel (b): extracted complex excess conductivity.  $\Delta\sigma_1$ , open symbols;  $\Delta\sigma_2$ , full dots. The arrow marks the choice of  $T_c$ . Panel (c): exact (open symbols) and approximate (full symbols)  $\Delta\sigma_1$ . Panel (d): percentage deviation  $\Delta$  of the approximate from the exact derivation of  $\Delta\sigma_1$ .